

UNR222x Series (UN222x Series)

Silicon NPN epitaxial planar type

For digital circuits

■ Features

- Costs can be reduced through downsizing of the equipment and reduction of the number of parts.
- Mini type package allowing easy automatic insertion through tape packing and magazine packing

■ Resistance by Part Number

		Marking Symbol (R ₁)		(R ₂)
• UNR2221 (UN2221)	9A	2.2 kΩ	2.2 kΩ	2.2 kΩ
• UNR2222 (UN2222)	9B	4.7 kΩ	4.7 kΩ	4.7 kΩ
• UNR2223 (UN2223)	9C	10 kΩ	10 kΩ	10 kΩ
• UNR2224 (UN2224)	9D	2.2 kΩ	10 kΩ	10 kΩ

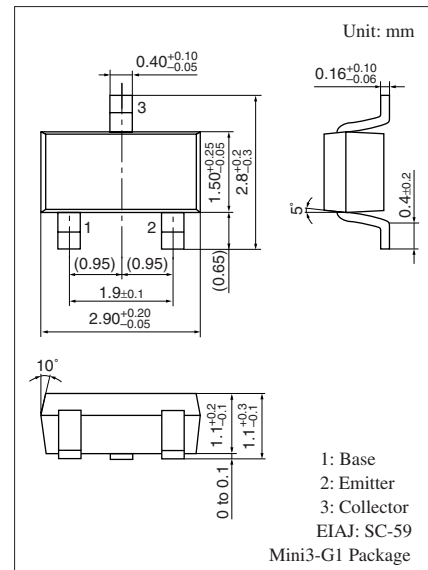
■ Absolute Maximum Ratings T_a = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	50	V
Collector-emitter voltage (Base open)	V _{CEO}	50	V
Collector current	I _C	500	mA
Total power dissipation	P _T	200	mW
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

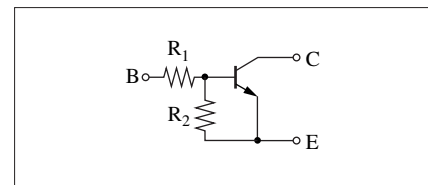
■ Electrical Characteristics T_a = 25°C ± 3°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	I _C = 10 μA, I _E = 0	50			V
Collector-emitter voltage (Base open)	V _{CEO}	I _C = 2 mA, I _B = 0	50			V
Collector-base cutoff current (Emitter open)	I _{CBO}	V _{CB} = 50 V, I _E = 0			1	μA
Collector-emitter cutoff current (Base open)	I _{CEO}	V _{CE} = 50 V, I _B = 0			1	μA
Emitter-base cutoff current (Collector open)	UNR2221	I _{EBO}			5	mA
	UNR2222					
	UNR2223/2224					
Forward current transfer ratio	UNR2221	h _{FE}	V _{CE} = 10 V, I _C = 100 mA	40		
	UNR2222			50		
	UNR2223/2224			60		
Collector-emitter saturation voltage	V _{CE(sat)}	I _C = 10 mA, I _B = 5 mA			0.25	V
Output voltage high-level	V _{OH}	V _{CC} = 5 V, V _B = 0.5 V, R _L = 500 Ω	4.9			V
Output voltage low-level	V _{OL}	V _{CC} = 5 V, V _B = 3.5 V, R _L = 500 Ω			0.2	V

Note) The part numbers in the parenthesis show conventional part number.



Internal Connection

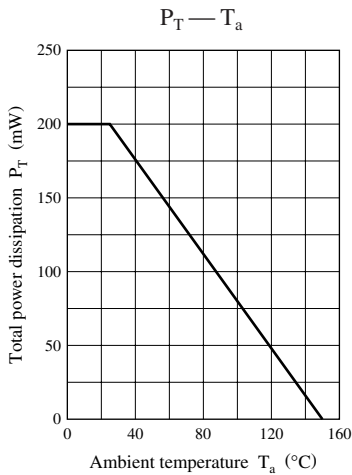


■ Electrical Characteristics (continued) $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

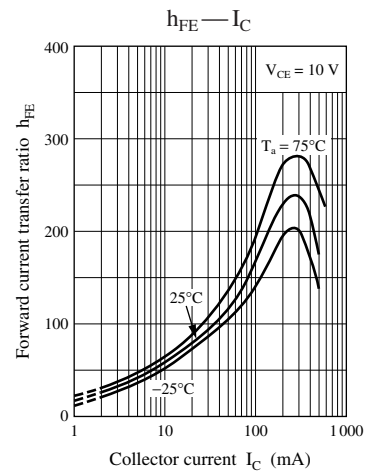
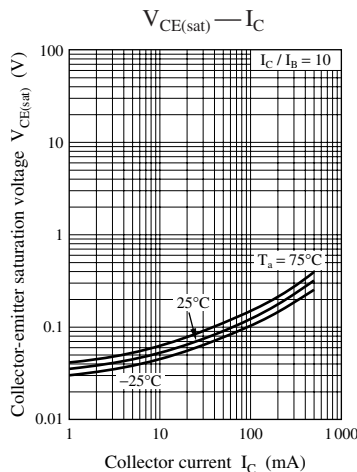
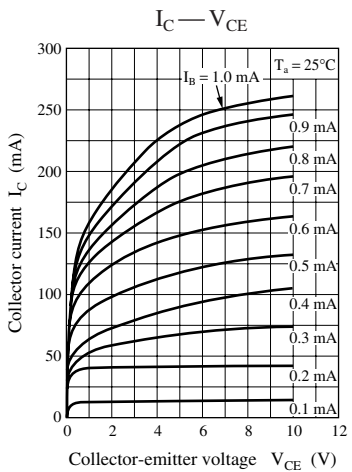
Parameter		Symbol	Conditions	Min	Typ	Max	Unit
Transition frequency		f_T	$V_{CB} = 10\text{ V}, I_E = -50\text{ mA}, f = 200\text{ MHz}$		200		MHz
Input resistance	UNR2221/2224	R_1		-30%	2.2	+30%	k Ω
	UNR2222				4.7		
	UNR2223				10		
Resistance ratio		R_1/R_2		0.8	1.0	1.2	—
	UNR2224			0.17	0.22	0.27	

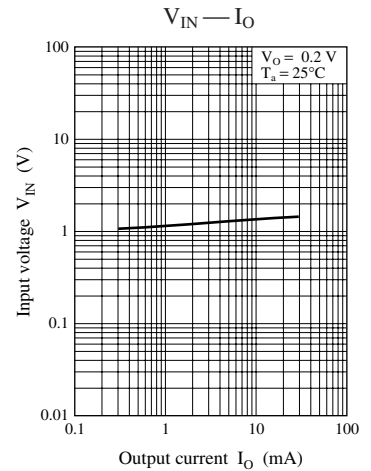
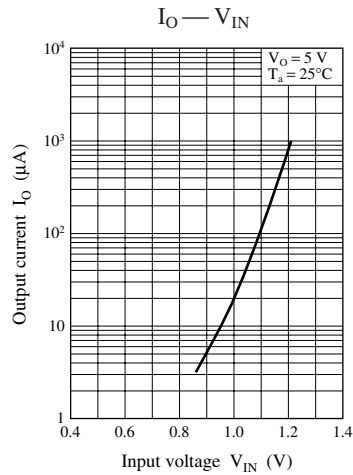
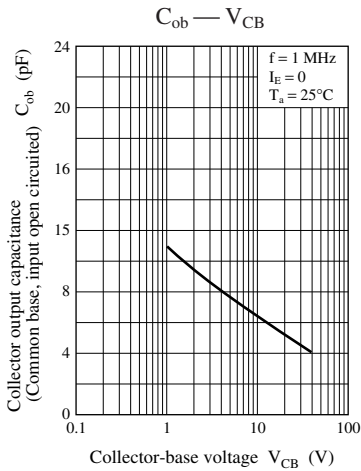
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

Common characteristics chart

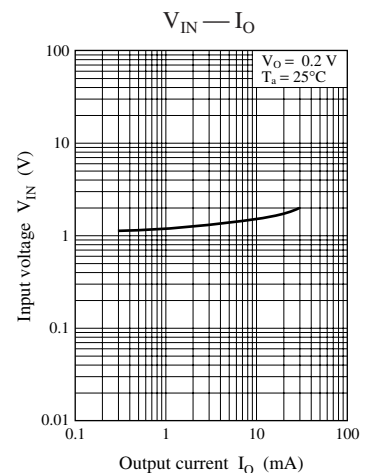
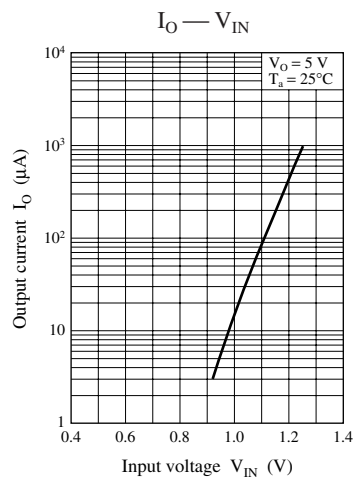
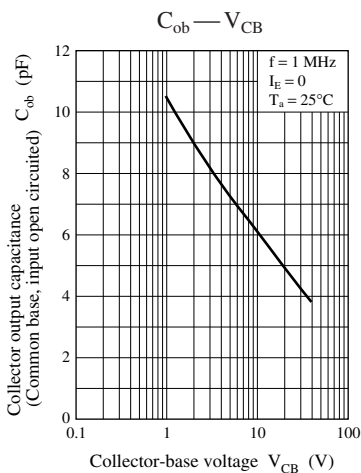
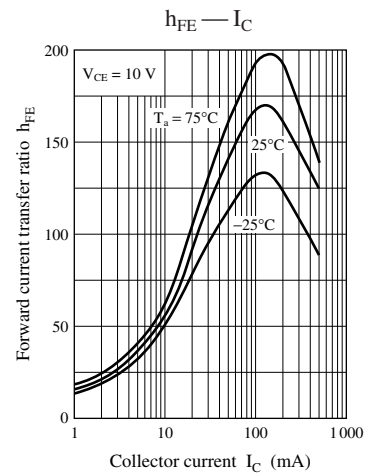
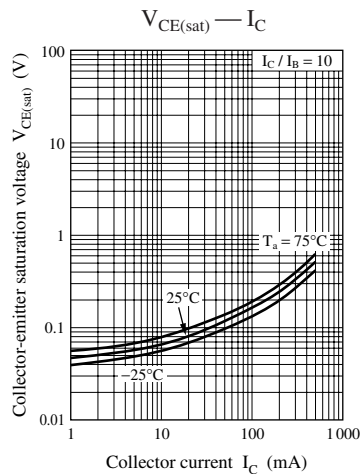
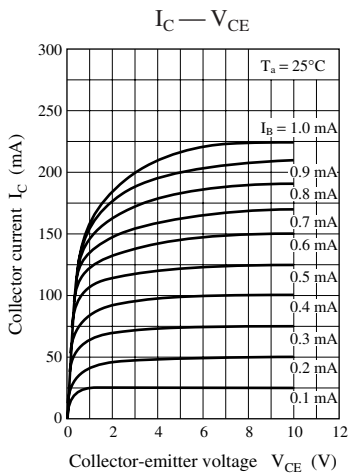


Characteristics charts of UNR2221

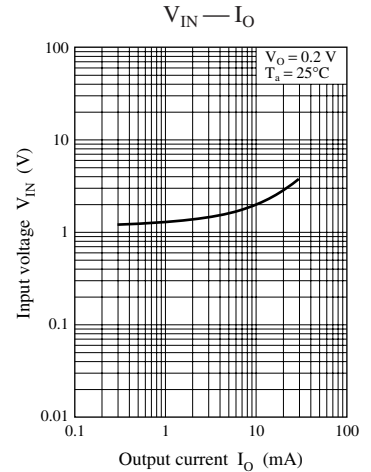
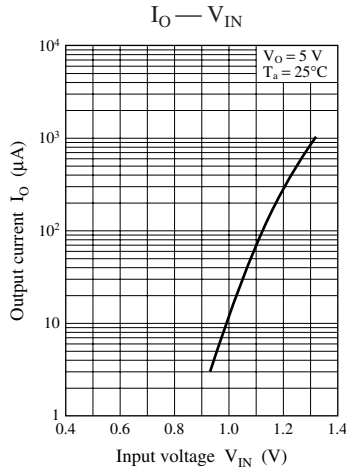
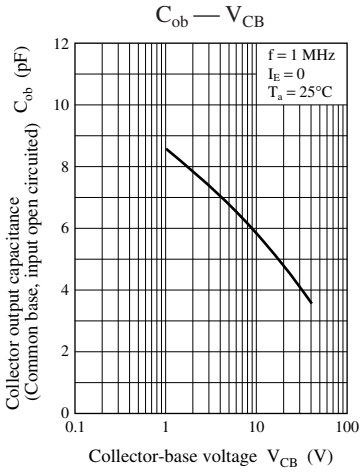
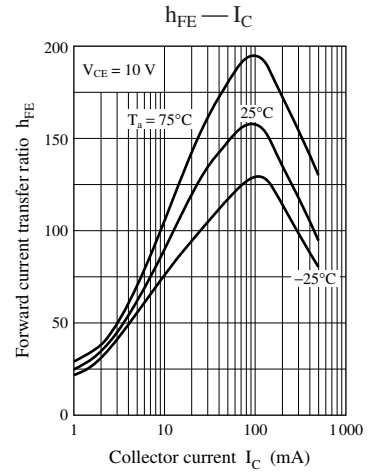
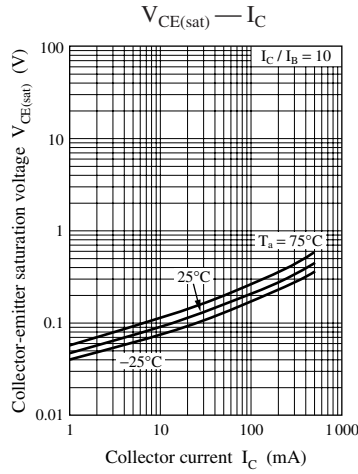
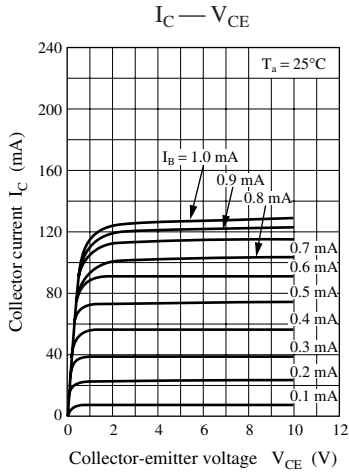




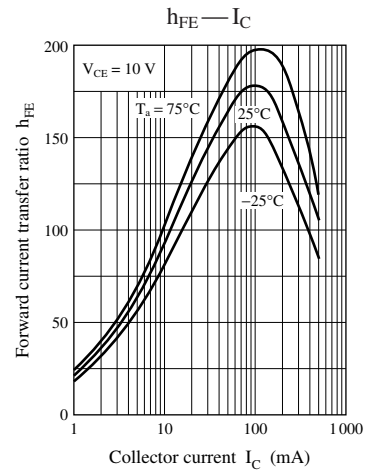
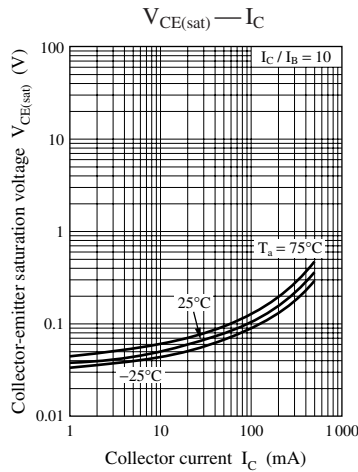
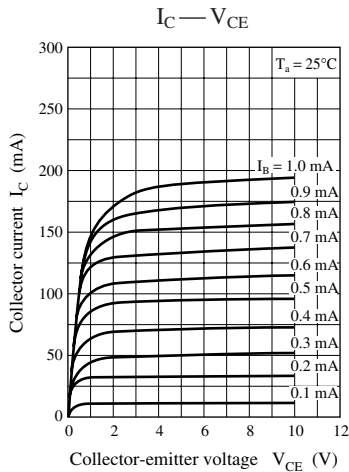
Characteristics charts of UNR2222

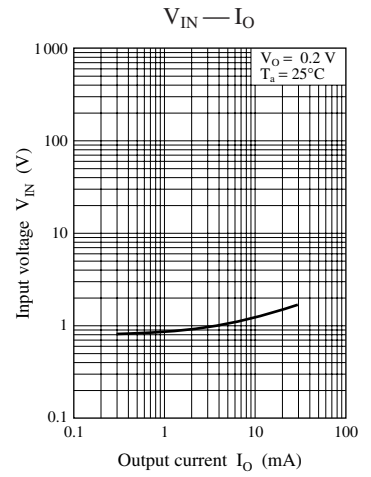
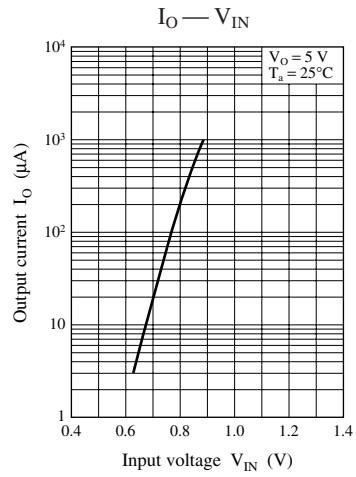
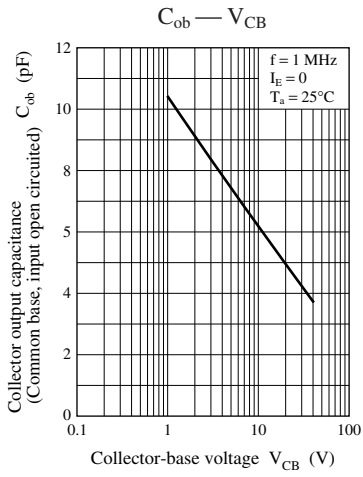


Characteristics charts of UNR2223



Characteristics charts of UNR2224





Request for your special attention and precautions in using the technical information and semiconductors described in this material

- (1) An export permit needs to be obtained from the competent authorities of the Japanese Government if any of the products or technical information described in this material and controlled under the "Foreign Exchange and Foreign Trade Law" is to be exported or taken out of Japan.
- (2) The technical information described in this material is limited to showing representative characteristics and applied circuits examples of the products. It neither warrants non-infringement of intellectual property right or any other rights owned by our company or a third party, nor grants any license.
- (3) We are not liable for the infringement of rights owned by a third party arising out of the use of the technical information as described in this material.
- (4) The products described in this material are intended to be used for standard applications or general electronic equipment (such as office equipment, communications equipment, measuring instruments and household appliances).
Consult our sales staff in advance for information on the following applications:
 - Special applications (such as for airplanes, aerospace, automobiles, traffic control equipment, combustion equipment, life support systems and safety devices) in which exceptional quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or harm the human body.
 - Any applications other than the standard applications intended.
- (5) The products and product specifications described in this material are subject to change without notice for modification and/or improvement. At the final stage of your design, purchasing, or use of the products, therefore, ask for the most up-to-date Product Standards in advance to make sure that the latest specifications satisfy your requirements.
- (6) When designing your equipment, comply with the guaranteed values, in particular those of maximum rating, the range of operating power supply voltage, and heat radiation characteristics. Otherwise, we will not be liable for any defect which may arise later in your equipment.
Even when the products are used within the guaranteed values, take into the consideration of incidence of break down and failure mode, possible to occur to semiconductor products. Measures on the systems such as redundant design, arresting the spread of fire or preventing glitch are recommended in order to prevent physical injury, fire, social damages, for example, by using the products.
- (7) When using products for which damp-proof packing is required, observe the conditions (including shelf life and amount of time let standing of unsealed items) agreed upon when specification sheets are individually exchanged.
- (8) This material may be not reprinted or reproduced whether wholly or partially, without the prior written permission of Matsushita Electric Industrial Co., Ltd.